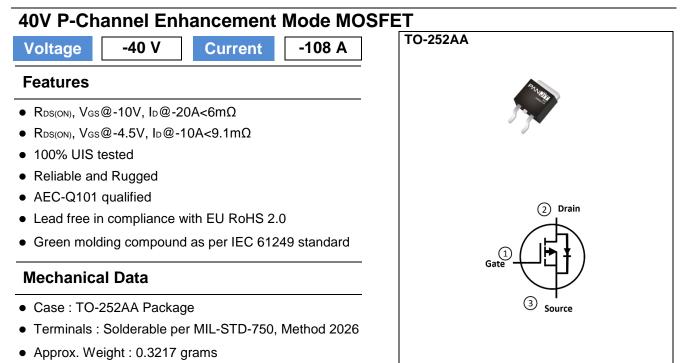
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#### Maximum Ratings and Thermal Characteristics (TA=25°C unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-40	- v	
Gate-Source Voltage		V <sub>GS</sub>	±25	V	
Continuous Drain Current <sup>(Note 3)</sup>	T <sub>C</sub> =25°C		-108		
	Tc=100°C	I <sub>D</sub>	-76	А	
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	-352		
Power Dissipation	T <sub>C</sub> =25°C	D-	125	14/	
	Tc=100°C	PD	63	- W	
Continuous Drain Current <sup>(Note 4)</sup>	T <sub>A</sub> =25°C		-16.7	•	
	T <sub>A</sub> =70°C	I <sub>D</sub>	-14	A	
Power Dissipation	T <sub>A</sub> =25°C	D-	3	- w	
	T <sub>A</sub> =70°C	PD	2.1	VV	
Single Pulse Avalanche Energy <sup>(Note</sup>	9 5)	Eas	156	mJ	
Operating Junction and Storage Temperature Range		Tj,Tstg	-55~175	°C	
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	$R_{ extsf{ heta}JC}$	1.2	°C/W	
	Junction to Ambient	R <sub>0JA</sub>	50		

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#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-40	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-2	-2.5	
Drain-Source On-State Resistance		V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	- 4.8 6		
	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-10A	-	7	9.1	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±25V, V <sub>DS</sub> =0V	-	-	±100	nA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	Qg		-	100	-	
Gate-Source Charge	Qgs	$V_{DS}$ =-32V, $I_{D}$ =-20A,	-	17	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-10V	-	23	-	
Input Capacitance	Ciss		-	5790	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V,	-	463	-	
Reverse Transfer Capacitance	Crss	f=1MHz	-	291	-	
Gate resistance	Rg	f=1MHz	-	11	-	Ω
Turn-On Delay Time	td <sub>(on)</sub>		-	10	-	
Turn-On Rise Time	tr	V <sub>DS</sub> =-32V, I <sub>D</sub> =-20A,	-	9	-	
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =-10V, R <sub>G</sub> =3Ω	-	211	-	ns
Turn-Off Fall Time	tf		-	150	-	1
Drain-Source Diode						
Diode Forward Current	Is	<sup>0</sup> 0	-	-	-108	
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>c</sub> =25°C	-	-	-352	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-20A, V <sub>GS</sub> =0V	-	-0.85	-1.3	V
Reverse Recovery Time	Trr	V <sub>GS</sub> =0V, I <sub>S</sub> =-20A	-	19	-	ns
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	6	-	nC

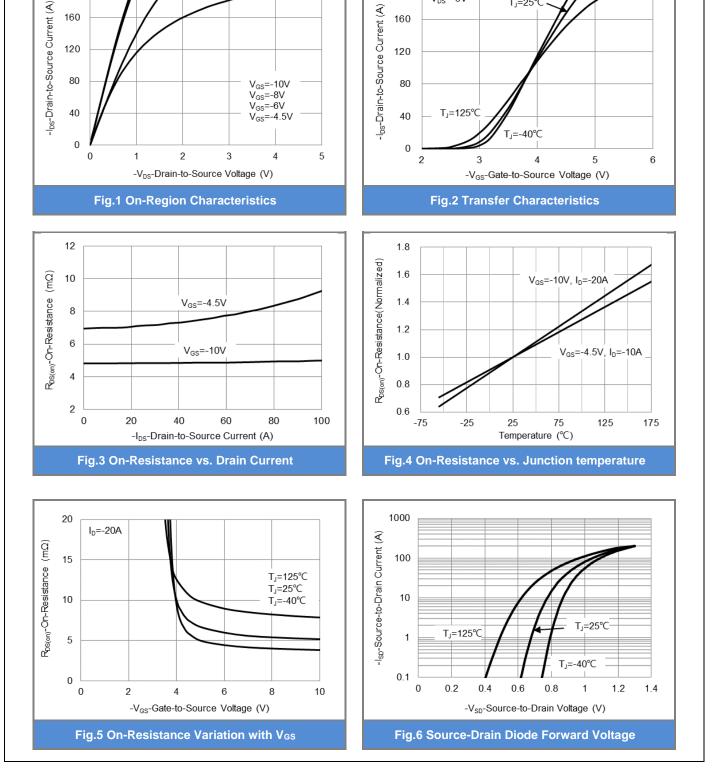
NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH,  $I_{AS}$ =-25A,  $V_{DD}$ =-30V,  $V_{GS}$ =-10V, Starting  $T_J$ =25°C.
- 6. Guaranteed by design, not subject to production testing.

April 18,2023

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200

V<sub>DS</sub>=-3V

TJ=25℃

# PJD95P04E-AU

**TYPICAL CHARACTERISTIC CURVES** 



200

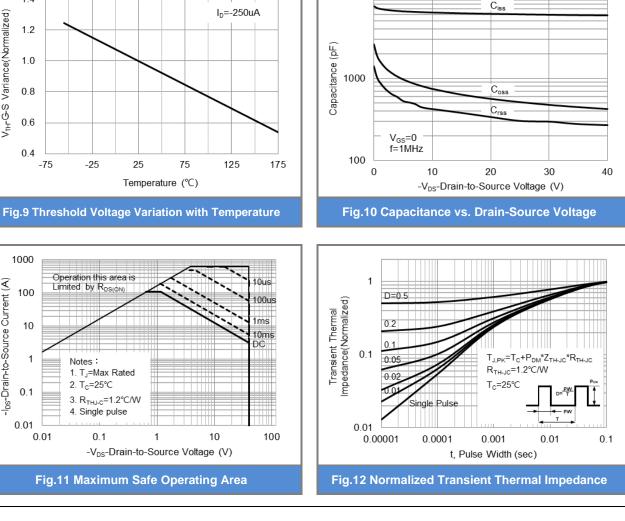
160



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-I<sub>bs</sub>-Drain-to-Source Current (A)



1.2

1.1

1.0

0.9

0.8

10000

-75

BV<sub>DSS</sub> Variance(Normalized)

In=-250uA

-25

25

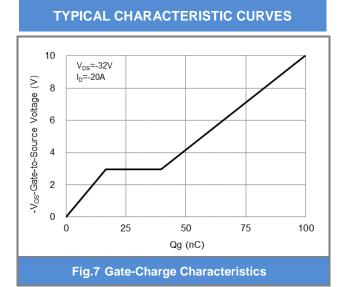
Fig.8 Breakdown Voltage Variation vs. Temperature

Temperature (°C)

75

125

175



### PJD95P04E-AU



1.4

V<sub>TH</sub>-G-S Variance(Normalized)

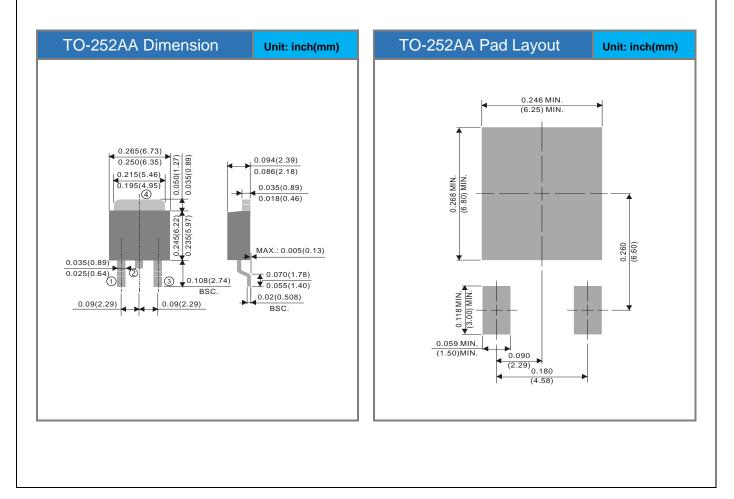




#### **Product and Packing Information**

Part No.	Package Type Packing Type		Marking	
PJD95P04E-AU	TO-252AA	3K pcs / 13" reel	D95P04E	

#### Packaging Information & Mounting Pad Layout





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